

COMPLIANT

Vishay Siliconix

Dual N-Channel 30-V (D-S) MOSFET

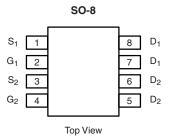
PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
30	0.0095 at V _{GS} = 10 V	12.2		
	0.016 at V _{GS} = 4.5 V	9.4		

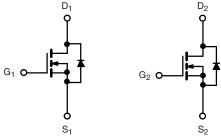
FEATURES

- Halogen-free Option Available
- TrenchFET[®] Power MOSFET
- 100 % R_g Tested

APPLICATIONS

- DC/DC Conversion
- Load Switching





N-Channel MOSFET

Ordering Information: Si4944DY-T1-E3 (Lead (Pb)-free) Si4944DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage			± 20		
	T _A = 25 °C	- I _D	12.2	9.3	•
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^a$	T _A = 85 °C		8.8	6.7	
Pulsed Drain Current		I _{DM}	30		A
Continuous Source Current (Diode Conduction) ^a	l	I _S	1.9 1.1		
Maximum Power Dissipation ^a	T _A = 25 °C	- P _D	2.3	1.3	W
	T _A = 85 °C		1.2	0.7	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	- R _{thJA} R _{thJF}	42	55	°C/W
Maximum Junction-to-Ambient ^a	Steady State		75	95	
Maximum Junction-to-Foot (Drain)	Steady State		19	25	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

MOSFET SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static	•		•	•	•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1		3	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA		
		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	μΑ		
Zero Gate Voltage Drain Current	IDSS	V_{DS} = 30 V, V_{GS} = 0 V, T_{J} = 85 °C			5			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			А		
		V _{GS} = 10 V, I _D = 12.2 A		0.0075	0.0095			
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 9.4 \text{ A}$	0.013 0.01		0.016	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 12.2 A		32		S		
Diode Forward Voltage ^a	V _{SD}	I _S = 1.9 A, V _{GS} = 0 V		0.8	1.2	V		
Dynamic ^b	•		•	•	•			
Total Gate Charge	Qg			13.5	21			
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 12.2 A		7.1		nC		
Gate-Drain Charge	Q _{gd}			4.7				
Gate Resistance	R _g	f = 1 MHz	0.5	1.0	1.7	Ω		
Turn-On Delay Time	t _{d(on)}			10	15			
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		10	15			
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong \text{1}$ A, V_GEN = 10 V, R_G = 6 Ω		40	60	ns		
Fall Time	t _f			12	20	1		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.9 A, dI/dt = 100 A/μs		45	70			

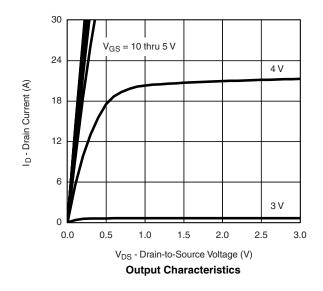
Notes:

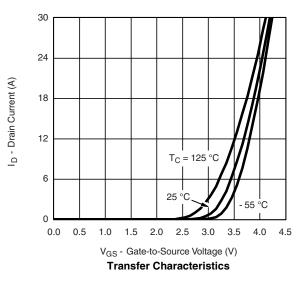
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

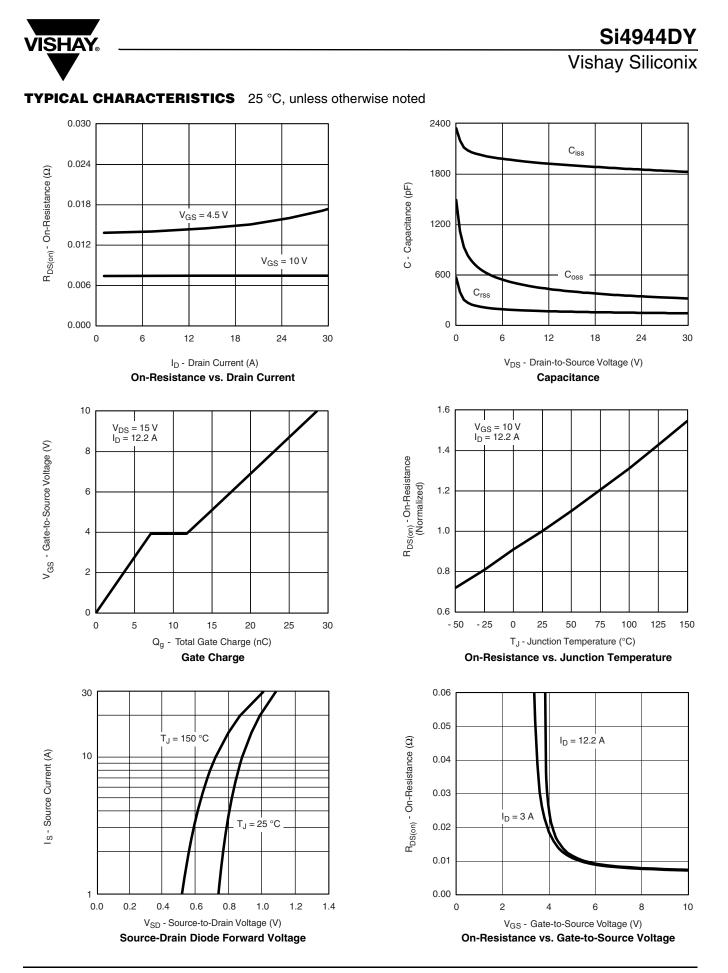
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





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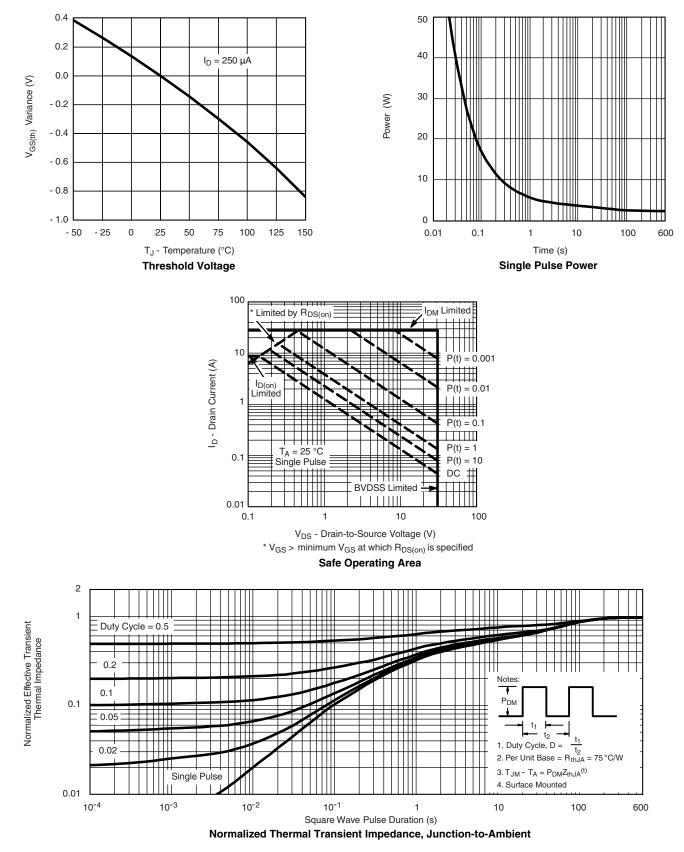
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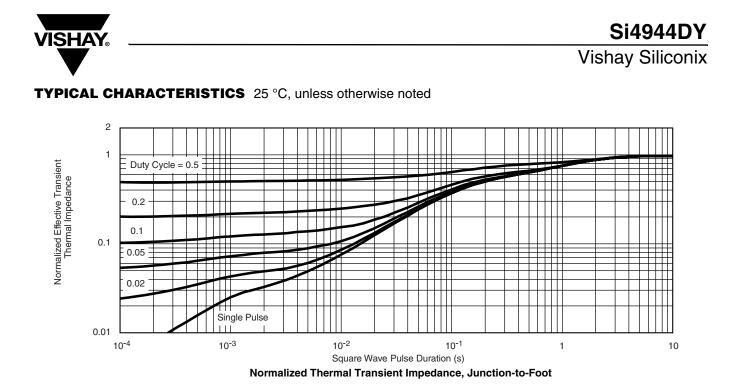
Si4944DY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72512.



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